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Key indicators

Single-crystal X-ray study

$T = 293$ K

Mean $\sigma(\text{C}-\text{C}) = 0.009$ Å

R factor = 0.059

wR factor = 0.163

Data-to-parameter ratio = 12.0

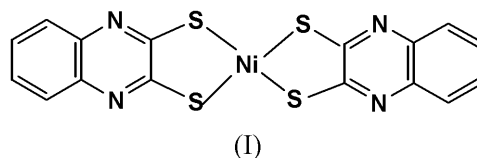
For details of how these key indicators were
automatically derived from the article, see
<http://journals.iucr.org/e>.

Bis(quinoxaline-2,3-dithiolato-*S,S'*)nickel(II)

The title complex, $[\text{Ni}(\text{C}_8\text{H}_4\text{N}_2\text{S}_2)_2]$, is a mononuclear nickel(II) complex in which the coordination about the Ni atom to the four S atoms of the two quinoxaline-2,3-dithiolate (qt) ligands is slightly distorted square planar. The molecule has a crystallographic inversion centre.

Comment

Thiolates are a subject of great interest in the chemistry of transition metal complexes (Krebs & Henkel, 1991). In an attempt to synthesize new complexes with novel electric and magnetic properties (Sheng *et al.*, 1998), we reacted $\text{Ni}(\text{CH}_3\text{COO})_2$ with quinoxaline-2,3-dithiol and the unpredicted title compound $[\text{Ni}(\text{qt})_2]$, (I), was isolated.



As shown in Fig. 1, (I) is a mononuclear nickel(II) complex consisting of two quinoxaline-2,3-dithiolate (qt) ligands and one Ni^{II} atom. The coordination about the Ni atom is slightly distorted square planar. The bond distances Ni—S are 2.1664 (15) and 2.1850 (15) Å. The angles S1—Ni—S2 and S1—Ni—S2A are 91.67 (5) and 88.33 (5)°, respectively.

Experimental

The title compound, (I), was obtained from the reaction of $\text{Ni}(\text{ac})_2$ (1 mmol) and qt (2 mmol) in CH_3OH (15 ml). $\text{Ni}(\text{Ac})_2$ (1 mmol) and qt (2 mmol) were sealed in a steel reactor with 15 ml of CH_3OH . The reaction mixture was heated to 363 K and maintained at this temperature for 72 h. After the reaction the solution was cooled to room temperature and a large amount of dark-brown and sheet-like crystals was obtained.

Crystal data

$[\text{Ni}(\text{C}_8\text{H}_4\text{N}_2\text{S}_2)_2]$
 $M_r = 443.23$
Monoclinic, $P2_1/c$
 $a = 6.6528$ (2) Å
 $b = 5.7251$ (2) Å
 $c = 20.9637$ (8) Å
 $\beta = 90.205$ (2)°
 $V = 798.46$ (5) Å³
 $Z = 4$

$D_x = 1.843$ Mg m⁻³
Mo $K\alpha$ radiation
Cell parameters from 1378
reflections
 $\theta = 1.9$ – 25.0°
 $\mu = 1.75$ mm⁻¹
 $T = 293$ (2) K
Sheet, black
 $0.24 \times 0.18 \times 0.08$ mm

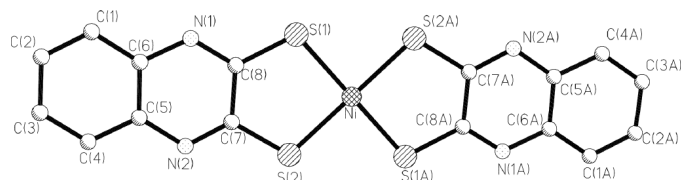


Figure 1
The structure of bis(quinoxaline-2,3-dithiolato-*S,S'*)nickel(II).

Data collection

SMART CCD diffractometer
 ω scans
Absorption correction: empirical
SHELXTL (Siemens, 1994)
 $T_{\min} = 0.492$, $T_{\max} = 0.794$
2114 measured reflections
1378 independent reflections

1022 reflections with $I > 2\sigma(I)$
 $R_{\text{int}} = 0.037$
 $\theta_{\max} = 25.0^\circ$
 $h = -7 \rightarrow 4$
 $k = -6 \rightarrow 3$
 $l = -22 \rightarrow 24$

Refinement

Refinement on F^2
 $R[F^2 > 2\sigma(F^2)] = 0.059$
 $wR(F^2) = 0.163$
 $S = 1.05$
1378 reflections
115 parameters

H-atom parameters constrained
 $w = 1/[\sigma^2(F_o^2) + (0.0965P)^2]$
where $P = (F_o^2 + 2F_c^2)/3$
 $(\Delta/\sigma)_{\max} < 0.001$
 $\Delta\rho_{\max} = 0.89 \text{ e } \text{\AA}^{-3}$
 $\Delta\rho_{\min} = -0.65 \text{ e } \text{\AA}^{-3}$

The positions of all H atoms were generated geometrically (C—H distance fixed at 0.96 Å), assigned isotropic displacement parameters and allowed to ride on their respective parent C atoms in the final cycle of least-squares refinement.

Data collection: *SMART* (Siemens, 1994); cell refinement: *SMART*; data reduction: *SAINT* (Siemens, 1994); program(s) used to solve structure: *SHELX97* (Sheldrick, 1997); program(s) used to refine structure: *SHELX97*; molecular graphics: *SHELXTL*; software used to prepare material for publication: *SHELXTL*.

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References

- Krebs, B. & Henkel, G. (1991). *Angew. Chem. Int. Ed. Engl.* **30**, 769–771.
- Sheldrick, G. M. (1997). *SHELX97*. University of Göttingen, Germany.
- Sheng, T. L., Wu, X. T., Zhang, W. J., Wang, Q. M., Gao, X. C. & Lin, P. (1998). *Chem. Commun.* pp. 263–264.
- Siemens (1994). *SMART*, *SAINT* and *SHELXTL* Siemens Analytical X-ray Instruments Inc., Madison, Wisconsin, USA.